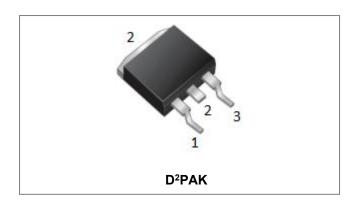






### **SB2540DC SCHOTTKY RECTIFIER**



#### **Features**

- 200°C T<sub>J</sub> operation
- Center tap configuration
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

# **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	40	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=95°C, rectangular wave form	12.5(Per Leg) 25(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	240	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 12.5A, Pulse, T <sub>J</sub> = 25 °C	0.45	0.55	V
(Per Leg) *	V <sub>F2</sub>	@ 12.5A, Pulse, T <sub>J</sub> = 125 °C	0.40	0.50	V
Reverse Current (Per Leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.01	1	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R_i} T_J = 125  ^{\circ}\text{C}$	7	30	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 \text{ °C}, f_{SIG} = 1MHz$	300	500	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

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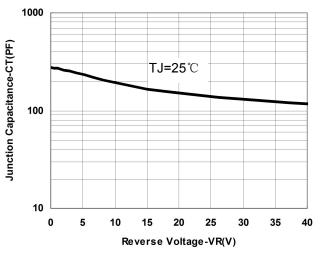


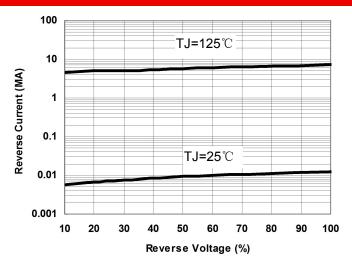


## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature				°C
at reduced reverse voltage	TJ	V <sub>R</sub> ≤80%V <sub>RRM</sub>	-55 to +150	
at reduced reverse voltage		V <sub>R</sub> ≤50%V <sub>RRM</sub>	-55 to +180	
in DC forward mode			-55 to +200	
Storage Temperature	T <sub>stg</sub>	-	-55 to +200	°C
Typical Thermal Resistance Junction to	R <sub>θJC</sub>	DC operation	2.0	°C/W
Case(Per Leg)				
Approximate Weight	wt	-	1.85	g
Case Style	D <sup>2</sup> PAK			

### **Ratings and Characteristics Curves**





**Fig.1-Typical Junction Capacitance** 

Fig.2-Typical Reverse Characteristics

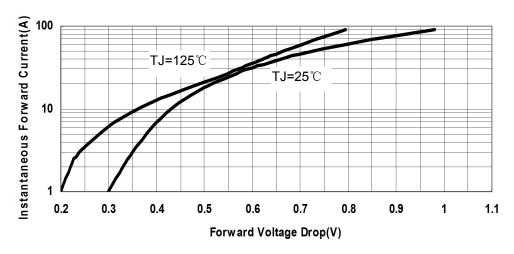


Fig.3-Typical Instantaneous Forward Voltage Characteristics

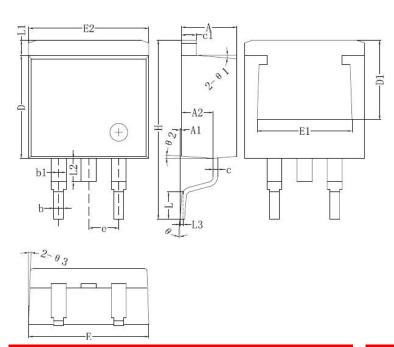
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#### **Mechanical Dimensions D<sup>2</sup>PAK**



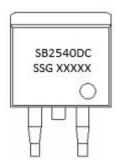
Symbol	Dimensions in millimeters			
_	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
<b>A</b> 1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

### **Ordering Information**

Device	Package	Shipping
SB2540DC	D <sup>2</sup> PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Marking Diagram**



Where XXXXX is YYWWL

 SB2540DC
 = Part Name

 SSG
 = SSG

 YY
 = Year

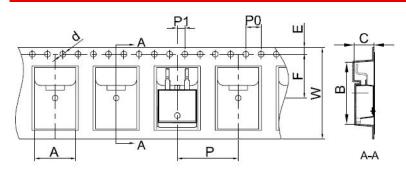
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# Carrier Tape Specification D<sup>2</sup>PAK



SYMBOL	Millimeters		
	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
Ε	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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